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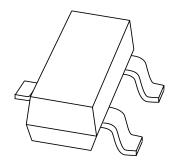
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Kind regards,

Team Nexperia

## **DISCRETE SEMICONDUCTORS**

# DATA SHEET



# BCV71; BCV72 NPN general purpose transistors

Product data sheet Supersedes data of 1997 Mar 11 1999 Apr 08



## NPN general purpose transistors

**BCV71**; **BCV72** 

#### **FEATURES**

• Low current (max. 100 mA)

• Low voltage (max. 60 V).

#### **APPLICATIONS**

• General purpose switching and amplification.

#### **DESCRIPTION**

NPN transistor in a SOT23 plastic package.

#### **MARKING**

TYPE NUMBER	MARKING CODE(1)
BCV71	K7*
BCV72	K8*

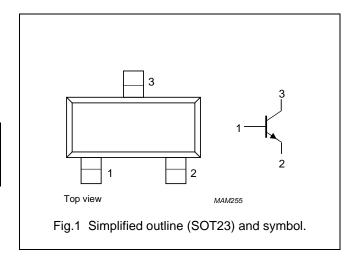
#### Note

1. \* = p: Made in Hong Kong.

\* = t : Made in Malaysia.

#### **PINNING**

PIN	DESCRIPTION	
1	base	
2	emitter	
3	collector	



#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	_	80	V
V <sub>CEO</sub>	collector-emitter voltage	open base; I <sub>C</sub> = 2 mA	_	60	V
$V_{EBO}$	emitter-base voltage	open collector	-	5	V
I <sub>C</sub>	collector current (DC)		_	100	mA
I <sub>CM</sub>	peak collector current		-	200	mA
I <sub>BM</sub>	peak base current		-	200	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	_	250	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C

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# NPN general purpose transistors

BCV71; BCV72

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	500	K/W

#### Note

1. Transistor mounted on an FR4 printed-circuit board.

#### **CHARACTERISTICS**

 $T_i = 25$  °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CBO</sub>	collector cut-off current	I <sub>E</sub> = 0; V <sub>CB</sub> = 20 V	_	_	100	nA
		$I_E = 0$ ; $V_{CB} = 20 \text{ V}$ ; $T_j = 100 ^{\circ}\text{C}$	_	Ī-	10	μА
I <sub>EBO</sub>	emitter cut-off current	I <sub>C</sub> = 0; V <sub>EB</sub> = 5 V	_	Ī-	100	nA
h <sub>FE</sub>	DC current gain	$I_C = 10 \mu A; V_{CE} = 5 V$				
	BCV71		_	90	_	
	BCV72		_	150	_	
	DC current gain	I <sub>C</sub> = 2 mA; V <sub>CE</sub> = 5 V				
	BCV71		110	-	220	
	BCV72		200	_	450	
V <sub>CEsat</sub>	collector-emitter saturation	I <sub>C</sub> = 10 mA; I <sub>B</sub> = 0.5 mA	_	120	250	mV
	voltage	$I_C = 50 \text{ mA}; I_B = 2.5 \text{ mA}$	_	210	_	mV
V <sub>BEsat</sub>	base-emitter saturation	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$	_	750	_	mV
	voltage	$I_C = 50 \text{ mA}; I_B = 2.5 \text{ mA}$	_	850	_	mV
V <sub>BE</sub>	base-emitter voltage	I <sub>C</sub> = 2 mA; V <sub>CE</sub> = 5 V	550	-	700	mV
C <sub>c</sub>	collector capacitance	I <sub>E</sub> = i <sub>e</sub> = 0; V <sub>CB</sub> = 10 V; f = 1 MHz	_	2.5	_	pF
f <sub>T</sub>	transition frequency	I <sub>C</sub> = 10 mA; V <sub>CE</sub> = 5 V; f = 100 MHz	100	-	_	MHz
F	noise figure	$I_C$ = 200 μA; $V_{CE}$ = 5 V; $R_S$ = 2 kΩ; $f$ = 1 kHz; $B$ = 200 Hz	_	-	10	dB

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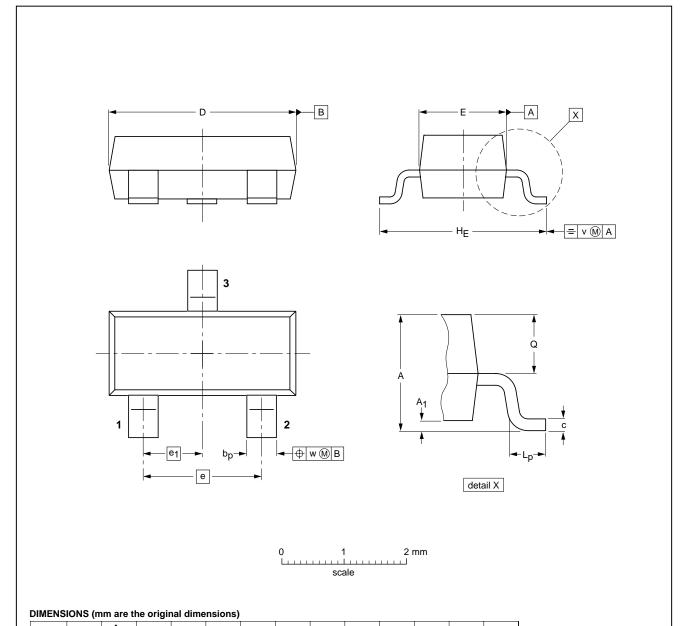
# NPN general purpose transistors

BCV71; BCV72

#### **PACKAGE OUTLINE**

Plastic surface mounted package; 3 leads

SOT23



OUTLINE		REFERENCES		EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT23		TO-236AB				<del>97-02-28</del> 99-09-13

e<sub>1</sub>

0.95

1.9

 ${\sf H}_{\sf E}$ 

 $L_{p}$ 

0.45

Q

0.55 0.45 w

0.1

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3.0 2.8

 $b_p$ 

0.48

0.15

Α

mm

max.

0.1

### NPN general purpose transistors

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#### **DATA SHEET STATUS**

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

#### Notes

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#### **Customer notification**

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

#### **Contact information**

For additional information please visit: http://www.nxp.com
For sales offices addresses send e-mail to: salesaddresses@nxp.com

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